

View Online at <https://aerobasegroup.com/nsn/5961-00-905-2719>

**Inclosure Material:**

Metal all transistor

**Overall Length:**

1.803 inches all transistor

**Mounting Facility Quantity:**

1 all transistor

**Internal Configuration:**

Junction contact all transistor

**Electrode Internally-electrically Connected To Case:**

Collector all transistor

**Internal Junction Configuration:**

Npn all transistor

**Component Function Relationship:**

Matched

**Component Name And Quantity:**

2 transistor

**Mounting Method:**

Threaded stud all transistor

**Overall Width Across Flats:**

0.875 inches all transistor

**Semiconductor Material:**

Silicon all transistor

**Voltage Rating In Volts Per Characteristic:**

100.0 collector to base voltage/static/emitter open all transistor and 100.0 collector to emitter voltage/static/base open all transistor and 15.0 emitter to base voltage, static, collector open all transistor

**Current Rating Per Characteristic:**

7.50 amperes source cutoff current all transistor and 30.00 amperes source cutoff current all transistor

**Power Rating Per Characteristic:**

200.0 watts small-signal input power, common-collector preset all transistor

**Maximum Operating Temperature Per Measurement Point:**

175.0 degrees celsius junction all transistor

**Terminal Type And Quantity:**

1 threaded stud all transistor and 2 tab, solder lug all transistor

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fiig:**

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